CMUT2222A

SURFACE MOUNT NPN SILICON TRANSISTOR



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMUT2222A type is an NPN silicon transistor manufactured by the epitaxial planar process, epoxy molded in an ULTRAmini™ surface mount package, designed for small signal general purpose and switching applications.

MARKING CODE: PC1



MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	75	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	I _C	600	mA
Power Dissipation	P_{D}	250	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	500	°C/W

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I _{CBO}	V _{CB} =60V		10	nA
ICBO	V _{CB} =60V, T _A =125°C		10	μΑ
ICEV	V_{CE} =60V, V_{EB} =3.0V		10	nA
I _{EBO}	V _{EB} =3.0V		10	nA
BV CBO	I _C =10μA	75		V
BV CEO	I _C =10mA	40		V
BVEBO	I _E =10μA	6.0		V
V _{CE} (SAT)	I _C =150mA, I _B =15mA		0.3	V
V _{CE(SAT)}	I_C =500mA, I_B =50mA		1.0	V
V _{BE} (SAT)	I_C =150mA, I_B =15mA	0.6	1.2	V
V _{BE(SAT)}	I_C =500mA, I_B =50mA		2.0	V
h _{FE}	V_{CE} =10V, I_{C} =0.1mA	35		
hFE	V_{CE} =10V, I_{C} =1.0mA	50		
hFE	V_{CE} =10V, I_{C} =10mA	75		
h _{FE}	V_{CE} =10V, I_{C} =150mA	100	300	
hFE	V_{CE} =1.0V, I_{C} =150mA	50		
h _{FE}	V_{CE} =10V, I_{C} =500mA	40		

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CMUT2222A

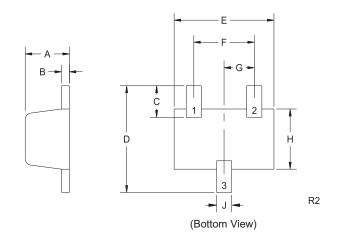


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ELECTRICAL CHARACTERISTICS - Continued: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
f _T	V _{CE} =20V, I _C =20mA, f=100MHz	300		MHz
C _{ob}	V _{CB} =10V, I _E =0, f=1.0MHz		8.0	pF
C _{ib}	V_{EB} =0.5V, I_{C} =0, f=1.0MHz		25	pF
h _{ie}	V_{CE} =10V, I_{C} =1.0mA, f=1.0kHz	2.0	8.0	kΩ
h _{ie}	V_{CE} =10V, I_{C} =10mA, f=1.0kHz	0.25	1.25	kΩ
h _{re}	V _{CE} =10V, I _C =1.0mA, f=1.0kHz		8.0	x10 ⁻⁴
h _{re}	V_{CE} =10V, I_{C} =10mA, f=1.0kHz		4.0	x10 ⁻⁴
h _{fe}	V_{CE} =10V, I_{C} =1.0mA, f=1.0kHz	50	300	
h _{fe}	V_{CE} =10V, I_{C} =10mA, f=1.0kHz	75	375	
h _{oe}	V_{CE} =10V, I_{C} =1.0mA, f=1.0kHz	5.0	35	μS
h _{oe}	V_{CE} =10V, I_{C} =10mA, f=1.0kHz	25	200	μS
rb'C _C	V _{CB} =10V, I _E =20mA, f=31.8MHz		150	ps
NF	V_{CE} =10V, I_{C} =100 μ A, R_{S} =1.0 $k\Omega$, f=1.0 kHz		4.0	dB
t_d	V_{CC} =30V, V_{BE} =0.5V, I_{C} =150mA, I_{B1} =15mA		10	ns
t _r	V_{CC} =30V, V_{BE} =0.5V, I_{C} =150mA, I_{B1} =15mA		25	ns
t _s	V_{CC} =30V, I_{C} =150mA, I_{B1} = I_{B2} =15mA		225	ns
t _f	V_{CC} =30V, I_{C} =150mA, I_{B1} = I_{B2} =15mA		60	ns

SOT-523 CASE - MECHANICAL OUTLINE



DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
Α	0.023	0.031	0.58	0.78
В	0.002	0.008	0.04	0.20
С	0.013	0.021	0.34	0.54
D	0.059	0.067	1.50	1.70
E	0.059	0.067	1.50	1.70
F	0.035	0.043	0.90	1.10
G	0.020		0.50	
Н	0.031	0.039	0.78	0.98
J	0.010	0.014	0.25	0.35

SOT-523 (REV: R2)

LEAD CODE:

- 1) Base
- 2) Emitter
- 3) Collector

MARKING CODE: PC1

R3 (9-February 2010)



OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
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- Special wafer diffusions
- · PbSn plating options
- · Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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